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Reinvestigation of the Uranium(3.5+) Rare-Earth Oxysulfides "(UO)₂LnS₃" (Ln = Yb, Y)

Geng Bang Jin,[†] Eun Sang Choi,[‡] and James A. Ibers*,[†]

[†]Department of Chemistry, Northwestern University, 2145 Sheridan Road, Evanston, Illinois 60208-3113, and *Department of Physics and National High Magnetic Field Laboratory, Florida State University, Tallahassee,

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Dark-red square plates of the previously reported compounds "(UO)₂LnS₃" (Ln = Yb, Y) have been synthesized by solid-state reactions of UOS and YbS or Y2S3 with Sb2S3 as a flux at 1273 K. The structure of these isotypic compounds was reinvestigated by single-crystal X-ray diffraction methods and an inductively coupled plasma experiment. The actual formula of " $(UO)_2LnS_3$ " (Ln = Yb, Y) is $(U_{0.5}Ln_{0.5}O)_2LnS_3$, that is, $ULn_2O_2S_3$, which can be charge-balanced with U⁴⁺ and Ln³⁺. The layered structure comprises (U/Ln)O₄S₄ square antiprisms alternating with LnS₆ octahedra. U and Ln1 atoms disorder on the eight-coordinate metal position, but Ln2 atoms occupy the six-coordinate metal position exclusively. UYb₂O₂S₃ is a modified Curie—Weiss paramagnet between 293 and 32 K, below which part of the paramagnetic moments go through a possible ferromagnetic transition. The band gaps of $ULn_2O_2S_3$ (Ln = Yb, Y) are around 2 eV.

Introduction

Layered ternary metal oxychalcogenides have been extensively studied because of their electronic and magnetic properties. Because of the differences in the oxophilicity and chalcophilicity of the metals, oxides and chalcogenides often form individual layers with distinct electronic properties. A combination of these layers results in interesting physical properties. For example, the LnCuOQ compounds (Ln = rare-earth metal; Q = S, Se, Te), consisting of alternating charge-carrying Cu/Q layers and insulating Ln/O layers, are promising transparent p-type conductors.

Compared to other layered metal oxychalcogenides, those containing U have been much less explored. The diffuse nature of 5f electrons of U can lead to diverse electronic and magnetic properties. For example, the UOQ compounds (Q = S, Se) are semiconductors and antiferromagnets that display considerable magnetic anisotropy.⁶⁻⁹ However, uranium oxychalcogenides are very difficult to synthesize because of the high stability of uranium oxides. The compounds denoted as $(UO)_2LnS_3$ $(Ln = Gd-Lu, Y)^{10,11}$ and (UOS)₄LuS¹² are the only reported layered uranium oxychalcogenides besides UOQ (Q = S, Se, Te). $^{8,13-15}$

The structures described as (UO)₂ErS₃¹¹ and (UOS)₄LuS¹² are closely related. The U atoms are surrounded by a combination of either eight or nine S and O atoms, and the Ln atoms are surrounded by six S atoms to form distinct UOS and LnS layers. In the crystal structure of (UO)₂ErS₃, there is only one independent U position and there are no S-S bonds. Charge balance then leads to the formal oxida-

^{*}To whom correspondence should be addressed. E-mail: ibers@chem. northwestern.edu.

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of U in (UOS)₄LuS are 3.5+ and 4.0+. Because of the unusual oxidation state of 3.5+ for U, we have resynthesized $(UO)_2LnS_3(Ln = Yb, Y)$ and reinvestigated their structures. Here we show that the compounds are actually ULn₂O₂S₃ (Ln = Yb, Y), in which charge balance is achieved with U⁴⁺ and Ln³⁺. We also report optical and magnetic properties of these compounds.

Experimental Section

Syntheses. UO₂ (Strem Chemicals, 99.8%), YbS (ESPI, 99.9%), ε -Yb₂S₃ (Alfa-Aesar, 99.9%), Y₂S₃ (Alfa-Aesar, 99.9%), S (Alfa-Aesar, 99.99%), and Sb (Aldrich, 99.5%) were used as received. Sb₂S₃ was prepared from the direct reaction of the elements in a sealed fused-silica tube at 1123 K. UOS was prepared by a solid-gas reaction among UO₂, S, and C at 1213 K. ¹⁶ The purities of YbS, ε -Yb₂S₃, Y₂S₃, UOS, and Sb₂S₃ were confirmed by powder X-ray diffraction measurements. Although the original syntheses¹⁰ were carried out at 1770-2173 K, we developed a lower-temperature synthetic route. Each reaction mixture of $ULn_2O_2S_3$ (Ln = Yb, Y) was thoroughly ground and placed in a fused-silica ampule, and then the ampule was flame-sealed under vacuum. It was first heated at 1273 K for 6 days. The resultant powder was ground with 0.100 g of Sb₂S₃ flux, the mixture was again placed in an ampule, and the ampule was then vacuum sealed. The reaction mixture was reheated to 1273 K in 40 h, kept at 1273 K for 8 days, cooled to 773 K for 8 days, and then cooled to 298 K in 8 h. The ULn₂O₂S₃ compounds are stable in air.

For UYb₂O₂S₃, the starting materials were UOS (0.147 g, 0.515 mmol) and YbS (0.053 g, 0.258 mmol). The reaction product included dark-red square plates of $UYb_2O_2S_3$ and yellow needles of $\epsilon\text{-}Yb_2S_3$.¹⁷ Also in the tube were unreacted black UOS powder and black Sb₂S₃ crystals. The majority of the UYb₂O₂S₃ crystals were found in the form of clumps, with ε -Yb₂S₃ needle clusters growing on the top and UOS powder growing on the bottom. The yield of UYb2O2S3 was about 20% based on Yb.

UY₂O₂S₃ was synthesized from a mixture of UOS (0.161 g, 0.563 mmol) and Y_2S_3 (0.039 g, 0.140 mmol). The reaction product comprised long needles of UY₄O₃S₅^{1/8} and dark-red square plates of UY₂O₂S₃. The yields of UY₄O₃S₅ and UY₂O₂S₃ were about 10% and 5%, respectively, based on Y. Unreacted black UOS powder, orange Y₂S₃ crystals, and black Sb₂S₃ crystals were also present.

Analyses. Several dark-red plates of $ULn_2O_2S_3$ (Ln = Yb, Y) were examined with an energy-dispersive X-ray (EDX)equipped Hitachi S-3400 scanning electron microscope. EDX analysis showed the presence of U, Ln, and S but no evidence of Sb. O could not be detected because its emission line is below the lower limit of the instrument.

An inductively coupled plasma (ICP) measurement to quantify the U:Yb ratio was conducted on a sample of about 0.5 mg of single crystals of UYb₂O₂S₃. The dark-red plates were carefully selected and cleaned before being dissolved in 0.72 mL of a 68–70% HNO₃ solution. The solution was diluted to 10 mL and analyzed on a Varian VISTA-MPX instrument. Seven U and Yb standard solutions were used. The ratio U:Yb was determined to be 0.59(1).

Powder X-ray Diffraction Measurements. Powder X-ray diffraction patterns were collected with a Rigaku Geigerflex powder X-ray diffractometer with the use of Cu Kα radiation ($\lambda = 1.5418 \text{ Å}$).

Crystal-Structure Determinations. Single-crystal X-ray diffraction data for UYb2O2S3 and UY2O2S3 were collected with the use of graphite-monochromatized Mo K α radiation (λ = 0.71073 Å) at 100 K on a Bruker Smart-1000 CCD diffractometer. ¹⁹ The crystal-to-detector distance was 5.023 cm. Crystal decay was monitored by recollecting 50 initial frames at the end of the data collection. Data were collected by a scan of 0.3° in ω in groups of 606 frames at φ settings of 0°, 90°, 180°, and 270°. The exposure times for UYb2O2S3 and UY2O2S3 were 40 and 50 s frame⁻¹, respectively. The collection of the intensity data was carried out with the program SMART.¹⁹ Cell refinement and data reduction were carried out with the use of the program APEX2.²⁰ A Leitz microscope equipped with a calibrated traveling micrometer eyepiece was employed to measure accurately the dimensions of each data crystal. Face-indexed absorption corrections were performed numerically with the use of the program *XPREP*. ²¹ Then the program *SADABS*¹⁹ was employed to make incident beam and decay corrections.

The SHELXL suite of programs was used for all calculations.²¹ Beginning with the model for "(UOS)₂ErS", the isotropic refinement of "(UOS)2YbS" proceeded smoothly to an R_1 index of 0.030. An unusual feature was that the isotropic displacement sphere for U was larger than that for Yb. (This is also true for the earlier structure determination of "(UOS)₂ErS".) However, this same model did not refine for (UOS)₂YS. The structure was solved again with the program SHELXS. It became clear that a successful model could only be found if the scattering density at the U position were reduced significantly. An unrestricted anisotropic model in which U and Y atoms were disordered at the U site refined successfully and led to U:Y = 0.506(6):1 (Table 1). The restricted refinement (U:Y = 0.5:1) gave the same result. The unrestricted and restricted refinements for the Yb compound are also shown in Table 1. Whereas the unrestricted refinement is slightly better, we do not consider it to be significantly so.

In all of these refinements, the displacement ellipsoids of atom S2, which is at the origin of the cell, remained positive-definite but were highly prolate. This is also true in the original structure determination of "(UO)₂ErS₃". It may be that there is some disorder in the position of atom S2; there is no evidence in any of these structure determinations to support a lower-symmetry space

The program $STRUCTURE\ TID\ Y^{22}$ was used to standardize the positional parameters. Additional experimental details are given in Table 2 and the Supporting Information.

Magnetic Susceptibility Measurements. As noted above, $UYb_2O_2S_3$ crystals grew together with ϵ - $Yb_2S_3^{17}$ and UOS. Large clusters of U2YbO2S3 crystals were crushed, and small clusters comprising 7.8 mg of UYb2O2S3 crystals were carefully collected and then ground. The X-ray diffraction pattern of the resultant powder confirmed that it was UYb₂O₂S₃ contaminated by a small amount of ε -Yb₂S₃. Neither UOS nor Sb₂S₃ was detected.

The powder sample was loaded into a polycarbonate capsule holder, which was then placed in a Quantum Design MPMS instrument. Direct-current susceptibility measurements were made from 2 to 300 K under zero-field-cooled (ZFC) and field-cooled (FC) conditions. The contribution of the diamagnetic background of the sample holder was removed using the experimental values from a separate run on an empty capsule. The temperature-independent background term

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Table 1. Least-Squares Refinements for ULn₂O₂S₃

compound	$R(F)^a$	$R_w(F^2)^b$	U:Yb
$\begin{array}{c} UYb_2O_2S_3 \\ UYb_2O_2S_3 \\ UY_2O_2S_3 \\ UY_2O_2S_3 \end{array}$	0.0256	0.076	0.5:1 (restricted)
	0.0238	0.0662	0.83(4):1 (unrestricted) ^c
	0.0162	0.0508	0.5:1 (restricted)
	0.0163	0.0507	0.506(6):1 (unrestricted)

 ${}^{a}R(F) = \sum_{||F_{o}| - |F_{c}||/\sum |F_{o}|} |F_{o}| \text{ for } F_{o}^{2} > 2\sigma(F_{o}^{2}). {}^{b}R_{w}(F_{o}^{2}) = \{\sum_{|w(F_{o}^{2} - F_{c}^{2})^{2}|/\sum wF_{o}^{4}|^{1/2}. w^{-1}} = \sigma^{2}(F_{o}^{2}) + (0.0321F_{o}^{2})^{2} \text{ for UYb}_{2}O_{2}S_{3}, w^{-1} = \sigma^{2}(F_{o}^{2}) + (0.02F_{o}^{2})^{2} \text{ for UY}_{2}O_{2}S_{3}. {}^{c}\text{ The ratio found from the ICP}$ measurement is 0.59(1):1.

Table 2. Crystal Data and Structure Refinements for ULn₂O₂S₃^a

	$UYb_2O_2S_3$	UY ₂ O ₂ S ₃
fw	712.29	544.03
a (Å)	3.7762(9)	3.8077(9)
$c(\mathring{A})$	20.691(5)	20.889(5)
$V(\mathring{A}^3)$	295.0(1)	302.9(1)
$\rho_{\rm c} ({\rm g cm}^{-3})$	8.018	5.966
$ \rho_{\rm c} ({\rm g cm}^{-3}) $ $ \mu ({\rm cm}^{-1}) $	597.61	465.95

^a For both structures, Z = 2, space group = I4/mmm, T = 100(2) K, and $\lambda = 0.71073$ Å. Values of R(F) and $R_w(F_0^2)$ are given in Table 1.

 (χ_0) was obtained either by extrapolating the χ vs 1/T curve to zero at high temperatures or by using the modified Curie—Weiss fitting at low temperatures.

A separate measurement was carried out on a sample of pure ε -Yb₂S₃ to ascertain its contribution, if any, to the magnetic measurements on the $UYb_2O_2S_3$ sample.

Single-Crystal Optical Measurements. Several red square plates of UYb2O2S3 and UY2O2S3 were selected and placed under light mineral oil on a glass slide. Optical absorption data were collected for each compound from 380 nm (3.27 eV) to 900 nm (1.38 eV) at 293 K with a Hitachi U6000 microscopic FT spectrophotometer. The absorbances of oil and glass were subtracted as a background.

Results

Syntheses. $UYb_2O_2S_3$ and $UY_2O_2S_3$ were originally prepared at high temperatures (>1773 K) through solidstate reactions between UOS and LnS or Ln₂S₃. ^{10,11} In the present study, efforts were made to lower the reaction temperature through the use of various fluxes, including alkali-metal halides, alkali-metal chalcogenides, and Sb₂S₃. No reactions were detected below 1123 K. Between 1123 and 1273 K, alkali-metal halides and chalcogenides were observed to etch the carbon-coated fused-silica tubes and react with the rare-earth sulfides to form ternary compounds. For example, the reaction of UOS and Yb₂S₃ with KCl flux at 1223 K produced K₃Yb₇S₁₂, which is isostructural to Rb₃Yb₇Se₁₂.²³ However, Sb₂S₃ was found to be inert throughout this entire temperature range. Upon heating of UOS and YbS with Sb₂S₃ at 1273 K for 3 weeks, small crystals of UYb₂O₂S₃ were successfully synthesized in about 20% yield. However, the crystals were coated with UOS and ε-Yb₂S₃. Complete separation of UYb₂O₂S₃ from these contaminants was not possible.

Two different products were formed from the reaction of UOS and Y₂S₃ with Sb₂S₃ as a flux. One was the desired product UY₂O₂S₃, which was obtained in about 5% yield. The other, which was obtained in about 10% yield, was

Figure 1. Two-dimensional-layered structure of $ULn_2O_2S_3$ (Ln = Yb, Y).

the new compound UY₄O₃S₅. ¹⁸ Most of the UY₂O₂S₃ crystals were mixed with UOS or Y₂S₃. Attempts to collect enough clean crystals for ICP and magnetic measurements failed.

Numerous variations in the starting materials and stoichiometries did not improve the yields of UYb₂O₂S₃ or UY₂O₂S₃ crystals.

Structures. The structure of the isostructural compounds UYb₂O₂S₃ and UY₂O₂S₃ is shown in Figure 1. It is constructed from alternating layers of double (U/Ln)-O₄S₄ layers and single edge-sharing LnS₆ octahedral layers. The U and Ln(1) atoms, which disorder on a site of symmetry 4mm, are connected to four O and four S atoms in a square antiprism. The Ln(2) atoms, located on a site of symmetry 4/mmm, are connected to six S atoms. Within the double (U/Ln)O₄S₄ layers, each U/LnO₄S₄ square antiprism shares one O and two S atoms with four identical neighbors in the ab plane to form a single layer and further connects to four other units from the adjacent single layer by sharing two O atoms.

The structure of $ULn_2O_2S_3$ (Ln = Yb, Y) and that characterized as " $(UOS)_4LuS$ "¹² are related to that of UOS, 13 as shown in Figure 2. The U atoms in UOS are surrounded by four O and five S atoms in a monocapped square antiprism. The structure of ULn₂O₂S₃ (Ln = Yb, Y) can be obtained by removing all of the capping U-S bonds in the UOS structure and inserting LnS₆ octahedral layers. The structure of (UOS)₄LuS can be obtained by removing half of the capping U-S bonds in the UOS structure and inserting LnS₆ octahedral layers. Therefore, half of the U atoms in the (UOS)₄LuS structure are still bonded to four O and five S atoms and half of them are bonded to four O and four S atoms.

Selected interatomic distances for UYb₂O₂S₃ and $UY_2O_2S_3$ are listed in Table 3. The U/Ln(1) disorder does not allow detailed comparisons to be made. However, the Ln(2)—S distances clearly show the effect of the lanthanide contraction. The Yb(2)-S distances of 2.631(5) and 2.6702(6) Å are consistent with those of 2.660-2.788 Å in τ -Yb₂S₃,²⁴ and the Y-S distances of 2.676(2) and

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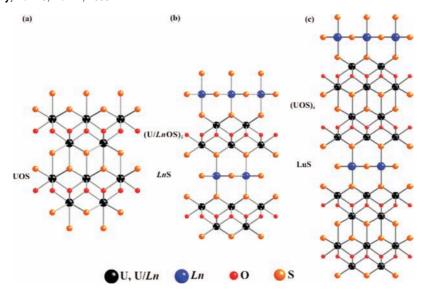


Figure 2. Views of the structures of (a) UOS, (b) $ULn_2O_2S_3$ (Ln = Yb, Y), and (c) (UOS)₄LuS down the b axis.

Table 3. Selected Interatomic Distances (Å) for ULn₂O₂S₃^{a,b}

	UYb ₂ O ₂ S ₃	UY ₂ O ₂ S ₃
$ \frac{U(1)/Ln(1)-O(1)\times 4}{U(1)/Ln(1)-S(1)\times 4} $ $ \frac{U(1)/Ln(1)-S(1)\times 4}{U(1)/Ln(1)-S(1)\times 4} $	2.28(2) 2.96(2)	2.29(1) 2.98(1)
$Ln(2)-S(1) \times 2$ $Ln(2)-S(2) \times 4$	2.631(5) 2.6702(6)	2.676(2) 2.6925(6)

 a U(1)/Ln(1)–O and U(1)/Ln(1)–S interatomic distances are truncated to two decimal places because of the U/Ln(1) disorder. The difference between the effective ionic radii of U $^{4+}$ and Yb $^{3+}$ is 0.02 Å and that between U $^{4+}$ and Y $^{3+}$ is 0.01 Å. $^{39-b}$ Restricted refinement.

2.6925(6) Å are in the range of those of 2.626(3) – 2.819(3) Å for δ -Y₂S₃.²⁵

Although bond-valence sums²⁶ are strictly empirical, they are often thought to provide an indication of formal oxidation states for various cations in solid-state compounds. In the present instance, the sums are as follows: for $UYb_2O_2S_3$, U(1) = 3.90, Yb(1) = 2.76, and Yb(2) = 3.25; for $UY_2O_2S_3$, U(1) = 3.76, Y(1) = 2.93, and Y(2) = 3.44.

Magnetic Susceptibility of UYb₂O₂S₃. Figure 3 shows the temperature dependence of the ZFC susceptibility χ and $1/\chi$ for UYb₂O₂S₃ at 0.1 T applied field. At both high temperatures (100 < T < 300 K) and low temperatures (1.8 < T < 8 K), the susceptibility of UYb₂O₂S₃ shows a modified Curie—Weiss temperature dependence (\sim 1/T). In the intermediate temperature range, the 1/T dependence starts to show deviation from the high-temperature side and a sudden increase of χ is observed below 32 K.

Before doing further analysis, we examined contributions from the possible magnetic impurities ε -Yb₂S₃ (detected from powder X-ray diffraction measurements) and UOS (not so detected). Both ε -Yb₂S₃²⁷ and UOS²⁸ are known to show a paramagnetic-to-antiferromagnetic phase transition at 7 and 55 K respectively. The dotted line of Figure 3 is $\chi(T)$ of UYb₂O₂S₃ after subtraction

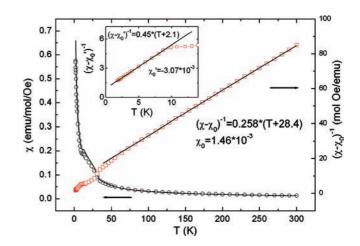


Figure 3. ZFC magnetic susceptibility χ vs T for UYb₂O₂S₃ under H=0.1 T. The line indicates a modified Curie—Weiss fitting for χ^{-1} for 100 < T < 300 K. The inset shows the inverse susceptibility at low temperatures with a linear fitting below 8 K. The line in the χ plot represents a hypothetical susceptibility of UYb₂S₂O₃ without ε -Yb₂S₃ and UOS impurities.

from the original data of contributions of 10 wt % ε -Yb₂S₃²⁹ and 5 wt % UOS.²⁸ Even though these quantities of impurities are overestimated, the two $\chi(T)$ curves are practically identical. This suggests that the 1/T dependence is an inherent property of UYb₂O₂S₃.

Nevertheless, the presence of two different magnetic ions (U⁴⁺ and Yb³⁺) in UYb₂O₂S₃ makes it difficult to separate their contributions to the magnetic moment. For instance, a full contribution of each of the free ions (3.6 $\mu_{\rm B}$ from U⁴⁺ and 4.9 $\mu_{\rm B}$ from Yb³⁺)³⁰ gives $\langle \mu \rangle = [\mu(U^{4+})^2 + 2\mu(Yb^{3+})^2]^{1/2} = 7.3 \ \mu_{\rm B}/{\rm fu}$, which is much larger than the observed value [5.6(2) $\mu_{\rm B}/{\rm fu}$]. In fact, the values of the effective moments in rare-earth and actinide compounds are often smaller than those for the free ion because of the crystalline electric field (CEF) effect. Usually 5f electrons

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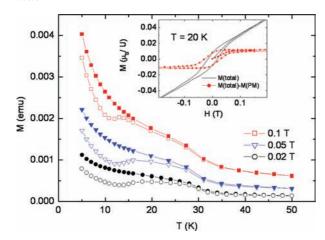


Figure 4. χ vs T for UYb₂O₂S₃ at different fields: ZFC (open symbols); FC (filled symbols). Inset: magnetization data taken at 20 K.

in actinides are more subject to the CEF because they tend to be less localized than the 4f electrons in rare earths. When the CEF lifts the degeneracy of the ground state of a Hund multiplet, the spin population at higher CEF levels will be decreased at finite temperatures, resulting in a reduced effective moment. The Curie-type susceptibility $(\chi \sim 1/T)$ can be observed even under the CEF effect. When the temperature is much smaller than the CEF splitting, the effective moment will be reduced. When it is much larger, the free-ion value will apply.

In UYb₂O₂S₃, the CEF will play different roles for U⁴⁺ and Yb³⁺ because U⁴⁺ (5f², ⁴H₃) is a non-Kramers ion with a less symmetric CEF environment and Yb³⁺ ($4f^{13}$, ${}^{2}F_{7/2}$) is a Kramers ion under a rather symmetric (octahedral YbS₆) CEF field. The observed 1/T dependence of χ at low temperatures should be mostly from the Kramers doublet of Yb³⁺, with the excited CEF level larger than the thermal energy. If we exploit the 1/T dependence by assuming a weak temperature dependence of χ of U⁴⁺ at low temperatures, then the effective moment of Yb³⁺ is about 3.0 μ_B . If we use this value for the $\chi \sim 1/T$ dependence at high temperatures, we obtain 3.7 $\mu_{\rm B}$ for the effective moment of \overline{U}^{4+} , which is very close to the free-ion value. However, we note that this is valid only with several conditions being satisfied: (1) χ of U⁴⁺ is weakly temperature-dependent from nonmagnetic CEF singlets at low temperatures; (2) the Yb³⁺ ground-state doublet is the only accessible energy level up to 300 K; (3) U⁴⁺ CEF splitting is smaller than ~100 K. Experiments involving other physical measurements would be needed to clarify the issues.

Now we turn our attention to the intermediate temperature range. The anomaly around 32 K likely arises from a ferromagnetic transition, as suggested by differences between ZFC and FC susceptibilities (Figure 4). The broad maximum of ZFC susceptibility between 13 and 20 K can be attributed to randomly oriented ferromagnetic domains. The magnetization data measured at 20 K (Figure 4 inset), which show the hysteresis and saturation of magnetization after subtraction of the paramagnetic background as estimated from the high-field region, are also typical of ferromagnetism. However, the saturation moment of 0.01 μ_B/U (or equivalently 0.005 μ_B/Yb) is much lower by 2 orders of magnitude than those of typical ferromagnetic U compounds. Very low saturation moments in actinide compounds are not unprecedented, but

they have been mostly found in U-d metal intermetallics.³¹ The models proposed for those compounds are not applicable to the present rare-earth compounds. Another possible cause for the anomaly around 32 K is the presence of ferromagnetic impurities that were below the level that could be detected by X-ray diffraction measurements. Impurity phases that could conceivably be present include ferromagnetic US ($T_c = 180 \text{ K}$), ³² ferromagnetic $U_3S_5(T_c = 29 \text{ K})$, and the antiferromagnetic phases UOS ($T_N = 55 \text{ K}$), $US_3(T_N = 50 \text{ K})$, $US_3(T_N = 50 \text{ K})$, $US_3(T_N = 50 \text{ K})$, and paramagnetic US₂. Among these, the only possible impurity responsible for the anomaly would be U_3S_5 . From the synthetic conditions, we consider U_3S_5 to be extremely unlikely.

Even with this uncertainty, it is useful to note the difference of the magnetic structure of UYb₂O₂S₃ from that of UOS, which is an antiferromagnet, with the U moment being aligned along the c axis in a type 1A stacking order (++--). In UOS, U atoms within each UO₄S₄ layer couple antiferromagnetically with other U atoms from adjacent layers through U-O-U interactions. These antiferromagnetic double UOS layers stack along the c axis, and this leads to long-range antiferromagnetic ordering. To obtain the structure of UYb₂O₂S₃, a YbS₆ octahedral layer is inserted between two double UOS layers and half of the U atoms in the UOS layers are replaced by Yb atoms. The U-U interactions between the double layers will thereby be weakened by the increased interlayer distance. Both U-U direct exchange and U-O-U superexchange within the double layer will be weakened by dilution. U-U couplings will become less important compared to possible Yb-U or Yb-Yb interactions that we speculate may give rise to this different magnetic behavior. A further understanding of the magnetic properties of this material requires measurements on a compound with the same structure but with nonmagnetic rare-earth atoms, namely, UY₂O₂S₃. Unfortunately, we were unable to synthesize the necessary quantity of this material.

Optical Properties. Single-crystal absorption data, collected on several samples of UYb2O2S3 and UY2O2S3, are reproducible. Typical spectra of ULn₂O₂S₃ are plotted together with that of UY₄O₃S₅¹⁸ in Figure 5. The fine structures near the absorption edge that arise from U f-f transitions are very similar in all three compounds. This is not surprising because the coordination environments of the U atoms are similar. Because of these f-f transitions, we can only estimate the band gaps to be around 2 eV, consistent with the dark-red colors of these compounds.

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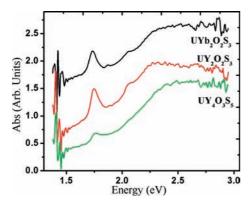


Figure 5. Single-crystal absorption spectra of $ULn_2O_2S_3$ (Ln = Yb, Y) and UY₄O₃S₅.

The decrease of the intensity for the transition around 1.75 eV in the order $UY_2O_2S_3$ to $UYb_2O_2S_3$ to $UY_4O_3S_5$ most probably results from the decrease of the U mass concentration.

Formal Oxidation States. One goal of the present work was to clarify the apparent oxidation state of U^{3.5+} in compounds that had been characterized previously as "(UO)2- LnS_3 " (Ln = Gd - Lu, Y), ¹⁰ on the basis of a crystal structure determination of (UO)₂ErS₃. 11 We were unable to solve the crystal structure of (UO)₂YS₃ starting with the Er model. Rather we discovered that there was U/Y disorder and that the compound is actually UY₂O₂S₃. Because there are no S-S interactions in the structure, charge balance leads to the formal oxidation states U⁴⁺ and Y³⁺. The ionic radii of these two ions differ by only 0.01 A, so disorder is not surprising. A similar analysis of the crystal structure of (UO)₂YbS₃ again reveals disorder and leads to an X-ray-derived ratio U:Yb = 0.83(3):1 (Table 1). This refinement is marginally better than one in which U:Yb is restricted to be 0.5:1, but given that the scattering powers of U (atomic number 92) and Yb (atomic number 70) are relatively close, we do not believe the two refinements differ significantly. Moreover, the U:Yb ratio of 0.59(1):1 derived from ICP measurements adds further credence to a formula of UYb₂O₂S₃, in which charge balance is achieved with U^{4+} and Yb^{3+} .

Crystals used for the present structure determinations were prepared from UOS and Ln₂S₃ with Sb₂S₃ as a flux at 1273 K followed by slow cooling, whereas those used in the structure determination of "(UO)₂ErS₃"¹¹ were prepared from UOS and ErS at 1770 K and rapid fusion at 2070 K followed by quenching. Are these the same materials structurally, or is it possible that the Er compound did not exhibit U/Er disorder but was indeed the $U^{3.5+}$ compound (UO)₂ErS₃? For the following reasons, we believe that there was U/Er disorder and that the compound was actually UEr₂O₂S₃: (1) The structure determinations show the same trends in displacement parameters; (2) the higher reaction conditions that generated the Er compound, both the higher temperatures and the quenching, should favor a disordered rather than an ordered structure; (3) reducing some of the U⁴⁺ to U³⁺ in the original preparation requires the oxidation of S^{2-} or Er^{2+} (if that is the actual oxidation state in the monosulfide). Given the great oxophilicity of U, its reduction in the presence of O^{2-} seems exceedingly

The question then arises as to the nature of the U atoms in the compound previously described as (UOS)₄LuS.¹² From the structure, charge balance is achieved with equal numbers of U atoms in the formal oxidation states of U^{3.5+} and U⁴⁺. Given the results on the present compounds, it is reasonable to expect that undetected U/Lu disorder is the source of " $U^{3.5+}$ ". The effective ionic radius of U⁴⁺ is 0.03 Å larger than that of Lu³⁺.39 U and Lu atoms could disorder on the eight-coordinate metal position with an occupancy of 0.5:0.5. Alternatively. U and Lu atoms could also disorder on both eightand nine-coordinate metal positions with an average occupancy of 0.75:0.25. In either instance, a new formula, U₃Lu₂O₄S₅, may be assigned in which charge balance is achieved with U⁴⁺ and Lu³⁺. Specifics of the possible disorder in (UOS)₄LuS must await a redetermination of its structure as well as an ICP analysis.

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Supporting Information Available: Crystallographic files in CIF format for UYb2O2S3 and UY2O2S3. This material is available free of charge via the Internet at http://pubs.acs.org.